



# Thyristor

$$V_{RRM} = 1600 \text{ V}$$

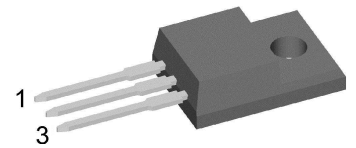
$$I_{TAV} = 23 \text{ A}$$

$$V_T = 1.42 \text{ V}$$

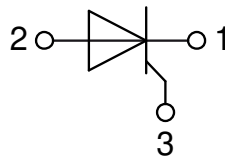
## Single Thyristor

Part number

**CMA30E1600PN**



Backside: Isolated



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

### Disclaimer Notice

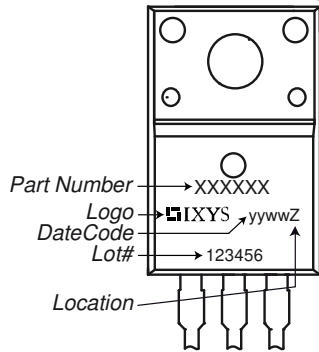
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| Thyristor      |  |   | Ratings                  |      |      |                  |
|----------------|--|---|--------------------------|------|------|------------------|
| Symbol         | Definition   | Conditions  | min.                     | typ. | max. | Unit             |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}C$  |                          |      | 1700 | V                |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^{\circ}C$  |                          |      | 1600 | V                |
| $I_{RD}$       | reverse current, drain current                       | $V_{R/D} = 1600 V$  | $T_{VJ} = 25^{\circ}C$   |      | 10   | $\mu A$          |
|                |  | $V_{R/D} = 1600 V$  | $T_{VJ} = 125^{\circ}C$  |      | 2    | mA               |
| $V_T$          | forward voltage drop                                 | $I_T = 30 A$  | $T_{VJ} = 25^{\circ}C$   |      | 1.42 | V                |
|                |  | $I_T = 60 A$  |                          |      | 1.80 | V                |
|                |  | $I_T = 30 A$  | $T_{VJ} = 125^{\circ}C$  |      | 1.42 | V                |
|                |  | $I_T = 60 A$  |                          |      | 1.92 | V                |
| $I_{TAV}$      | average forward current                              | $T_C = 40^{\circ}C$   | $T_{VJ} = 150^{\circ}C$  |      | 23   | A                |
| $I_{T(RMS)}$   | RMS forward current                                  | 180° sine   |                          |      | 36   | A                |
| $V_{T0}$       | threshold voltage                                    | } for power loss calculation only   | $T_{VJ} = 150^{\circ}C$  |      | 0.90 | V                |
| $r_T$          | slope resistance                                     |   |                          |      | 17   | m $\Omega$       |
| $R_{thJC}$     | thermal resistance junction to case                  |   |                          |      | 2.5  | K/W              |
| $R_{thCH}$     | thermal resistance case to heatsink                  |   |                          | 0.5  |      | K/W              |
| $P_{tot}$      | total power dissipation                              |   | $T_C = 25^{\circ}C$      |      | 50   | W                |
| $I_{TSM}$      | max. forward surge current                           | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}C$   |      | 260  | A                |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$              |      | 280  | A                |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}C$  |      | 220  | A                |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$              |      | 240  | A                |
| $I^2t$         | value for fusing                                     | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}C$   |      | 340  | A <sup>2</sup> s |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$              |      | 325  | A <sup>2</sup> s |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}C$  |      | 240  | A <sup>2</sup> s |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$              |      | 240  | A <sup>2</sup> s |
| $C_J$          | junction capacitance                                 | $V_R = 400 V \quad f = 1 \text{ MHz}$   | $T_{VJ} = 25^{\circ}C$   |      | 9    | pF               |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30 \mu s$  | $T_C = 150^{\circ}C$     |      | 10   | W                |
|                |  | $t_p = 300 \mu s$   |                          |      | 5    | W                |
| $P_{GAV}$      | average gate power dissipation                       |   |                          |      | 0.5  | W                |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 125^{\circ}C; f = 50 \text{ Hz}$  | repetitive, $I_T = 90 A$ |      | 150  | A/ $\mu s$       |
|                |  | $t_p = 200 \mu s; di_G/dt = 0.2 A/\mu s;$<br>$I_G = 0.2 A; V = \frac{2}{3} V_{DRM}$                                       | non-repet., $I_T = 30 A$ |      | 500  | A/ $\mu s$       |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V = \frac{2}{3} V_{DRM}$<br>$R_{GK} = \infty; \text{ method 1 (linear voltage rise)}$                                    | $T_{VJ} = 125^{\circ}C$  |      | 500  | V/ $\mu s$       |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6 V$   | $T_{VJ} = 25^{\circ}C$   |      | 1.3  | V                |
|                |  |   | $T_{VJ} = -40^{\circ}C$  |      | 1.6  | V                |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6 V$   | $T_{VJ} = 25^{\circ}C$   |      | 28   | mA               |
|                |  |   | $T_{VJ} = -40^{\circ}C$  |      | 50   | mA               |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$   | $T_{VJ} = 125^{\circ}C$  |      | 0.2  | V                |
| $I_{GD}$       | gate non-trigger current                             |   |                          |      | 1    | mA               |
| $I_L$          | latching current                                     | $t_p = 10 \mu s$  | $T_{VJ} = 25^{\circ}C$   |      | 90   | mA               |
|                |  | $I_G = 0.2 A; di_G/dt = 0.2 A/\mu s$  |                          |      |      |                  |
| $I_H$          | holding current                                      | $V_D = 6 V \quad R_{GK} = \infty$   | $T_{VJ} = 25^{\circ}C$   |      | 80   | mA               |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$<br>$I_G = 0.5 A; di_G/dt = 0.5 A/\mu s$   | $T_{VJ} = 25^{\circ}C$   |      | 2    | $\mu s$          |
| $t_q$          | turn-off time  | $V_R = 100 V; I_T = 30 A; V = \frac{2}{3} V_{DRM}$<br>$di/dt = 10 A/\mu s \quad dv/dt = 20 V/\mu s \quad t_p = 200 \mu s$ | $T_{VJ} = 125^{\circ}C$  |      | 150  | $\mu s$          |



| Package TO-220FP |  | Ratings                             |      |      |      |      |
|------------------|--|-------------------------------------|------|------|------|------|
| Symbol           | Definition   | Conditions                          | min. | typ. | max. | Unit |
| $I_{RMS}$        | RMS current  | per terminal                        |      |      | 35   | A    |
| $T_{VJ}$         | virtual junction temperature                                 |                                     | -40  |      | 150  | °C   |
| $T_{op}$         | operation temperature  |                                     | -40  |      | 125  | °C   |
| $T_{stg}$        | storage temperature  |                                     | -40  |      | 150  | °C   |
| <b>Weight</b>    |  |                                     |      | 2    |      | g    |
| $M_D$            | mounting torque  |                                     | 0.4  |      | 0.6  | Nm   |
| $F_C$            | mounting force with clip                                     |                                     | 20   |      | 60   | N    |
| $d_{Spp/App}$    | creepage distance on surface   striking distance through air | terminal to terminal                | 1.6  | 1.0  |      | mm   |
| $d_{Spb/Apb}$    |  | terminal to backside                | 2.5  | 2.5  |      | mm   |
| $V_{ISOL}$       | isolation voltage  | t = 1 second                        | 2500 |      |      | V    |
|                  |  | t = 1 minute                        | 2100 |      |      | V    |
|                  |  | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA |      |      |      |      |

**Product Marking**



**Part description**

- C = Thyristor (SCR)
- M = Thyristor
- A = (up to 1800V)
- 30 = Current Rating [A]
- E = Single Thyristor
- 1600 = Reverse Voltage [V]
- PN = TO-220ABFP (3)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | CMA30E1600PN    | CMA30E1600PN       | Tube          | 50       | 505254   |

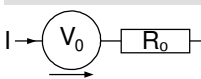
| Similar Part | Package                | Voltage class |
|--------------|------------------------|---------------|
| CMA30E1600PB | TO-220AB (3)           | 1600          |
| CMA30E1600PZ | TO-263AB (D2Pak) (2HV) | 1600          |
| CS22-12Io1M  | TO-220ABFP (3)         | 1200          |
| CLA30E1200PB | TO-220AB (3)           | 1200          |

|              |                      |      |
|--------------|----------------------|------|
| CLA30E1200PC | TO-263AB (D2Pak) (2) | 1200 |
| CLA30E1200HB | TO-247AD (3)         | 1200 |
| CS22-08Io1M  | TO-220ABFP (3)       | 800  |

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$

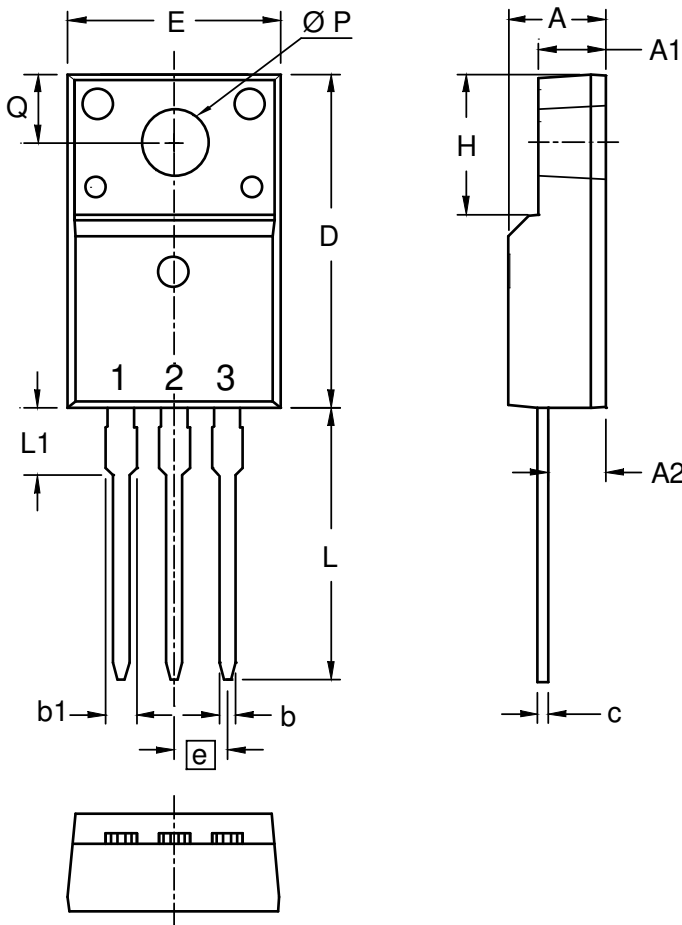


Thyristor

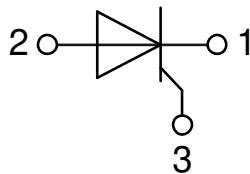
|              |                    |     |    |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage  | 0.9 | V  |
| $R_{0\ max}$ | slope resistance * | 14  | mΩ |



**Outlines TO-220FP**



| Dim. | Millimeters |       | Inches    |       |
|------|-------------|-------|-----------|-------|
|      | min         | max   | min       | max   |
| A    | 4.50        | 4.90  | 0.177     | 0.193 |
| A1   | 2.34        | 2.74  | 0.092     | 0.108 |
| A2   | 2.56        | 2.96  | 0.101     | 0.117 |
| b    | 0.70        | 0.90  | 0.028     | 0.035 |
| c    | 0.45        | 0.60  | 0.018     | 0.024 |
| D    | 15.67       | 16.07 | 0.617     | 0.633 |
| E    | 9.96        | 10.36 | 0.392     | 0.408 |
| e    | 2.54 BSC    |       | 0.100 BSC |       |
| H    | 6.48        | 6.88  | 0.255     | 0.271 |
| L    | 12.68       | 13.28 | 0.499     | 0.523 |
| L1   | 3.03        | 3.43  | 0.119     | 0.135 |
| ØP   | 3.08        | 3.28  | 0.121     | 0.129 |
| Q    | 3.20        | 3.40  | 0.126     | 0.134 |



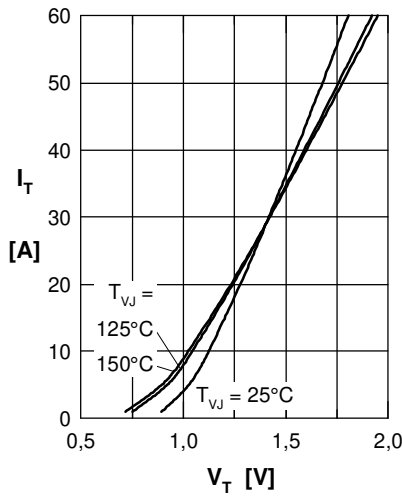
**Thyristor**


Fig. 1 Forward characteristics

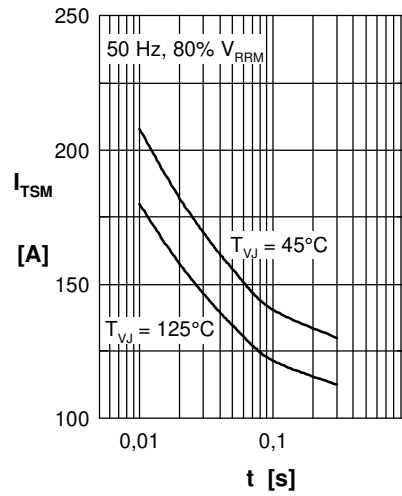
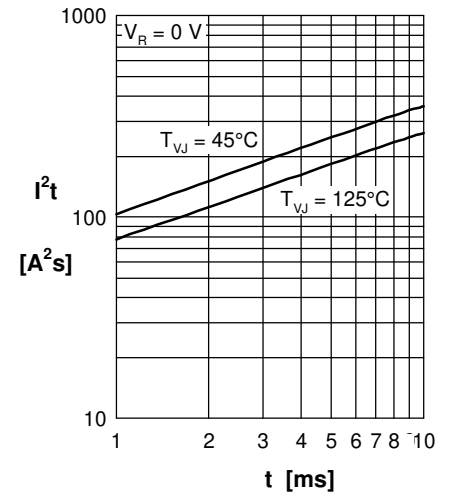
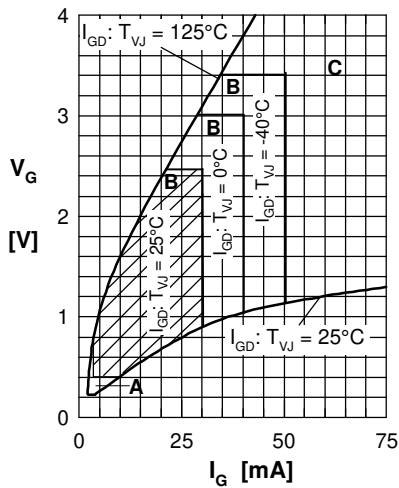
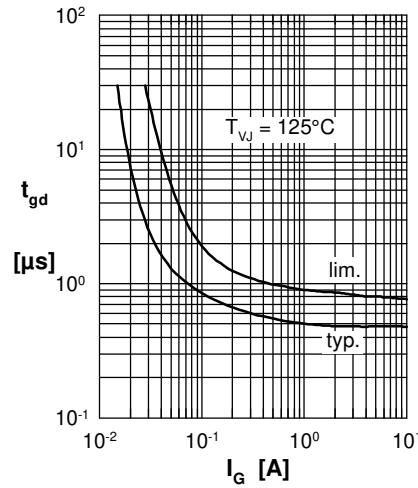
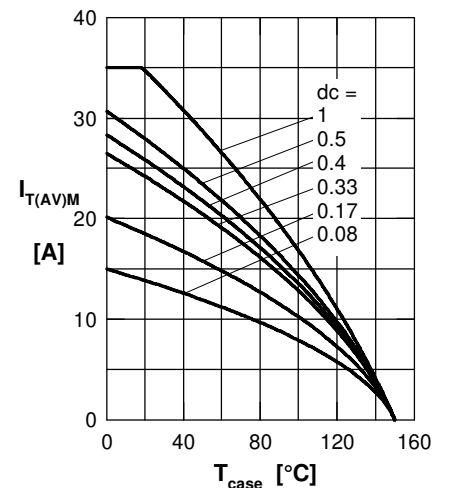

 Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

 Fig. 3  $I^2t$  versus time (1-10 s)

 Fig. 4 Gate voltage & gate current  
 Triggering: A = no; B = possible; C = safe

 Fig. 5 Gate controlled delay time  $t_{gd}$ 


Fig. 6 Max. forward current at case temperature

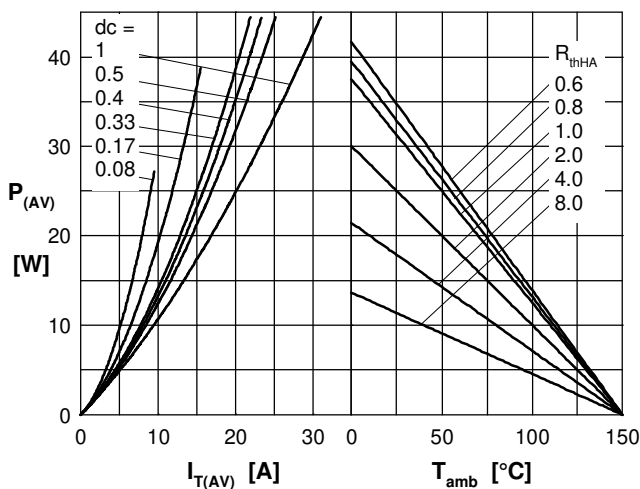
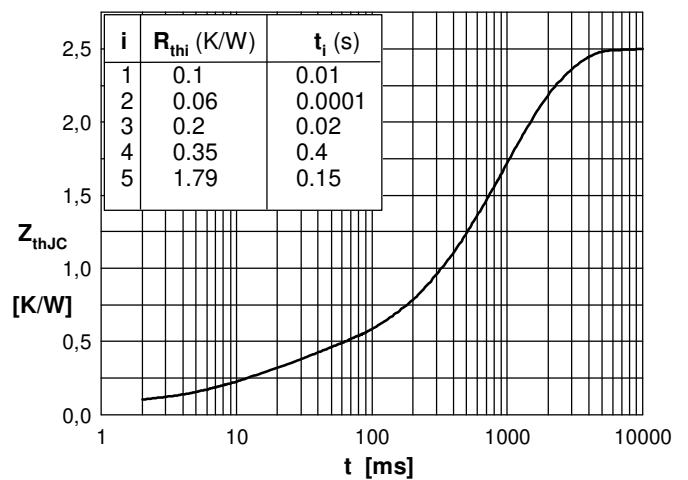

 Fig. 7a Power dissipation versus direct output current  
 Fig. 7b and ambient temperature


Fig. 7 Transient thermal impedance junction to case

